

FEATURES

Very low voltage noise: 2.8 nV/√Hz @ 1 kHz
Rail-to-rail output swing
Low input bias current: 2 nA maximum
Very low offset voltage: 12 μV typical
Low input offset drift: 0.6 μV/°C maximum
Very high gain: 120 dB
Wide bandwidth: 10 MHz typical
±5 V to ±18 V operation

APPLICATIONS

Precision instrumentation
PLL filters
Laser diode control loops
Strain gage amplifiers
Medical instrumentation
Thermocouple amplifiers

GENERAL DESCRIPTION

The AD8676 precision operational amplifier offers ultralow offset, drift, and voltage noise combined with very low input bias currents over the full operating temperature range. The AD8676 is a precision, wide bandwidth op amp featuring rail-to-rail output swings and very low noise. Operation is fully specified from ±5 V to ±15 V.

The AD8676 features a rail-to-rail output like that of the OP184, but with wide bandwidth and even lower voltage noise, combined with the precision and low power consumption like that of the industry-standard OP07 amplifier. Unlike other low noise, rail-to-rail op amps, the AD8676 has very low input bias current and low input current noise.

With typical offset voltage of only 12 μV, offset drift of 0.2 μV/°C, and noise of only 0.10 μV p-p (0.1 Hz to 10 Hz), the AD8676 is perfectly suited for applications where large error sources cannot be tolerated. Precision instrumentation, PLL and other precision filter circuits, position and pressure sensors, medical

instrumentation, and strain gage amplifiers benefit greatly from the very low noise, low input bias current, and wide bandwidth. Many systems can take advantage of the low noise, dc precision, and rail-to-rail output swing provided by the AD8676 to maximize SNR and dynamic range.

The smaller packages and low power consumption afforded by the AD8676 allow maximum channel density or minimum board size for space-critical equipment.

The AD8676 is specified for the extended industrial temperature range (−40°C to +125°C). The AD8676 is available in the 8-lead MSOP, and the popular 8-lead, narrow SOIC; both of which are lead-free packages. MSOP packaged devices are only available in tape and reel format.

For the single version of this ultraprecision, rail-to-rail op amp, see the [AD8675](#) data sheet.

PIN CONFIGURATIONS



Figure 1. 8-Lead SOIC_N (R-8)



Figure 2. 8-Lead MSOP (RM-8)

Rev. A

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REVISION HISTORY

4/08—Rev. 0 to Rev. A

| | |
|--|----|
| Changes to Table 1..... | 3 |
| Changes to Table 2..... | 4 |
| Changes to Figure 6, Figure 7, Figure 8 | 6 |
| Changes to Figure 9 through Figure 12 | 7 |
| Changes to Figure 21, Figure 22, and Figure 25 | 9 |
| Added Figure 26, Renumbered Sequentially | 9 |
| Changes to Figure 27 | 10 |
| Added Figure 28, Renumbered Sequentially | 10 |

10/06—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL SPECIFICATIONS

$V_S = \pm 5.0\text{ V}$, $V_{CM} = 0\text{ V}$, $V_O = 0\text{ V}$, $T_A = +25^\circ\text{C}$, unless otherwise specified.

Table 1.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|---|-------|----------|-------|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | | | 12 | 50 | μV |
| B Grade (SOIC) | | | | | 60 | μV |
| B Grade (MSOP) | | | | | 100 | μV |
| A Grade (SOIC, MSOP) | | | | | | |
| Offset Voltage | V_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 15 | 160 | μV |
| B Grade (SOIC, MSOP) | | | | | 250 | μV |
| A Grade (SOIC, MSOP) | | | | | | |
| Input Bias Current | I_B | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | -2 | | +2 | nA |
| | | | -5.5 | | +5.5 | nA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | -1 | | +1 | nA |
| | | | -2.8 | | +2.8 | nA |
| Input Voltage Range | | | -3.0 | | +3.0 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = -3.0\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 105 | 130 | | dB |
| | | | 105 | | | dB |
| Open-Loop Gain | A_{VO} | $R_L = 2\text{ k}\Omega$ to ground, $V_O = -3.5\text{ V to }+3.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 120 | 126 | | dB |
| | | | 117 | | | dB |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 0.2 | 0.6 | $\mu\text{V}/^\circ\text{C}$ |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $R_L = 10\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | +4.90 | +4.95 | | V |
| | | | +4.85 | | | V |
| | | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | +4.80 | +4.89 | | V |
| | | | +4.75 | | | V |
| Output Voltage Low | V_{OL} | $R_L = 10\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | -4.98 | -4.90 | V |
| | | | | | -4.85 | V |
| | | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | -4.91 | -4.86 | V |
| | | | | | -4.82 | V |
| Short-Circuit Limit | I_{SC} | | | +40 | | mA |
| Output Current | I_O | | | ± 20 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S = \pm 5.0\text{ V to } \pm 15.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 106 | 120 | | dB |
| | | | 106 | 120 | | dB |
| Supply Current/Amplifier | I_{SY} | $V_O = 0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 2.5 | 3.2 | mA |
| | | | | | 3.8 | mA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2\text{ k}\Omega$ | | 2.5 | | V/ μs |
| Gain Bandwidth Product | GBP | | | 10 | | MHz |
| NOISE PERFORMANCE | | | | | | |
| Voltage Noise | e_n p-p | 0.1 Hz to 10 Hz | | 0.1 | | $\mu\text{V p-p}$ |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ | | 2.8 | | nV/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 10\text{ Hz}$ | | 0.3 | | pA/ $\sqrt{\text{Hz}}$ |

AD8676

$V_S = \pm 15\text{ V}$, $V_{CM} = 0\text{ V}$, $V_O = 0\text{ V}$, $T_A = +25^\circ\text{C}$, unless otherwise specified.

Table 2.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|--|--------|----------|--------|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | | | 12 | 50 | μV |
| B Grade (SOIC) | | | | | 60 | μV |
| B Grade (MSOP) | | | | | 100 | μV |
| A Grade (SOIC, MSOP) | | | | | | |
| Offset Voltage | V_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 15 | 160 | μV |
| B Grade (SOIC, MSOP) | | | | | 250 | μV |
| A Grade (SOIC, MSOP) | | | | | | |
| Input Bias Current | I_B | | -2 | | +2 | nA |
| | | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | -4.5 | | +4.5 | nA |
| Input Offset Current | I_{OS} | | -1 | | +1 | nA |
| | | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | -2.8 | | +2.8 | nA |
| Input Voltage Range | | | -12.5 | | +12.5 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = -12.5\text{ V to }+12.5\text{ V}$ | 111 | 130 | | dB |
| | | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 107 | 130 | | dB |
| Open-Loop Gain | A_{VO} | $R_L = 2\text{ k}\Omega$ to ground, $V_O = -13.5\text{ V to }+13.5\text{ V}$ | 123 | 132 | | dB |
| | | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 117 | | | dB |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 0.2 | 0.6 | $\mu\text{V}/^\circ\text{C}$ |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $R_L = 10\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | +14.85 | +14.92 | | V |
| | | | +14.80 | | | V |
| | | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | +14.60 | +14.75 | | V |
| | | | +14.40 | | | V |
| Output Voltage Low | V_{OL} | $R_L = 10\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | -14.96 | -14.94 | V |
| | | | | | -14.90 | V |
| | | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | -14.85 | -14.75 | V |
| | | | | | -14.60 | V |
| Short-Circuit Limit | I_{SC} | | | +40 | | mA |
| Output Current | I_O | | | ± 20 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S = \pm 5.0\text{ V to } \pm 15.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 106 | 120 | | dB |
| | | | 106 | | | dB |
| Supply Current/Amplifier | I_{SY} | $V_O = 0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 2.7 | 3.4 | mA |
| | | | | | 4.2 | mA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 10\text{ k}\Omega$ | | 2.5 | | $\text{V}/\mu\text{s}$ |
| Gain Bandwidth Product | GBP | | | 10 | | MHz |
| NOISE PERFORMANCE | | | | | | |
| Voltage Noise | e_n p-p | 0.1 Hz to 10 Hz | | 0.1 | | $\mu\text{V p-p}$ |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ | | 2.8 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 10\text{ Hz}$ | | 0.3 | | $\text{pA}/\sqrt{\text{Hz}}$ |

ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
|--|---|
| Supply Voltage | $\pm 18\text{ V}$ |
| Input Voltage | $\pm V$ supply |
| Differential Input Voltage | $\pm 0.7\text{ V}$ |
| Output Short-Circuit Duration to GND | Indefinite |
| Storage Temperature Range | |
| RM, R Packages | -65°C to $+150^{\circ}\text{C}$ |
| Operating Temperature Range | -40°C to $+125^{\circ}\text{C}$ |
| Junction Temperature Range | |
| RM, R Packages | -65°C to $+150^{\circ}\text{C}$ |
| Lead Temperature Range (Soldering, 10 sec) | 300°C |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

Table 4. Thermal Resistance

| Package Type | θ_{JA} | θ_{JC} | Unit |
|-------------------|---------------|---------------|-----------------------------|
| 8-Lead MSOP (RM) | 210 | 45 | $^{\circ}\text{C}/\text{W}$ |
| 8-Lead SOIC_N (R) | 158 | 43 | $^{\circ}\text{C}/\text{W}$ |

POWER SEQUENCING

The op amp supplies must be established simultaneously with, or before, any input signals are applied. If this is not possible, the input current must be limited to 10 mA.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

±15 V and ±5 V, $T_A = 25^\circ\text{C}$, unless otherwise specified.

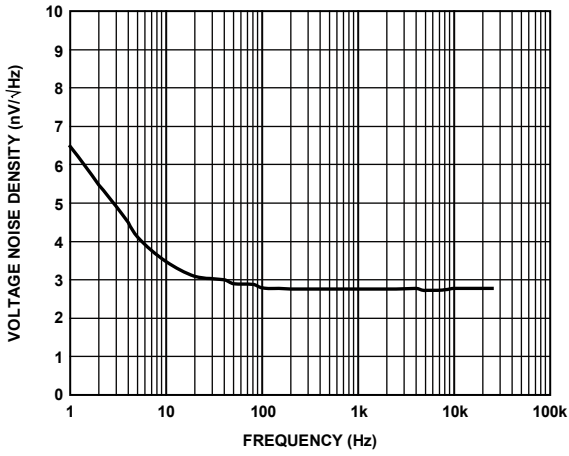


Figure 3. Voltage Noise Density vs. Frequency

06487-003

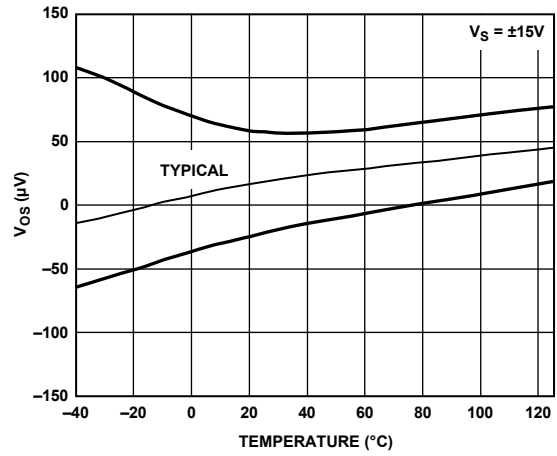


Figure 6. Offset Voltage vs. Temperature

06487-106

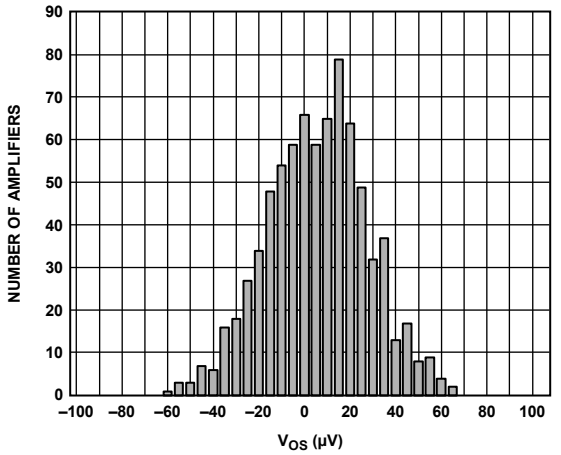


Figure 4. Input Offset Voltage Distribution

06487-004

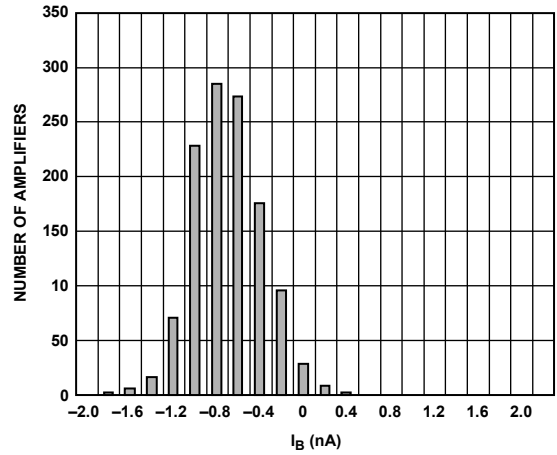


Figure 7. Input Bias Current, $V_{SY} = \pm 15\text{ V}$

06487-107

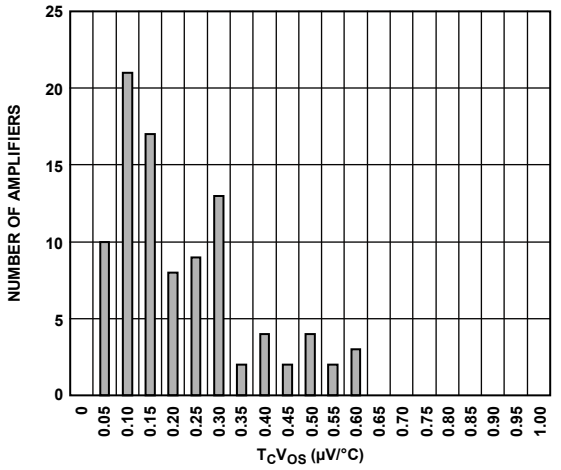


Figure 5. $T_c V_{OS}$ Distribution

06487-005

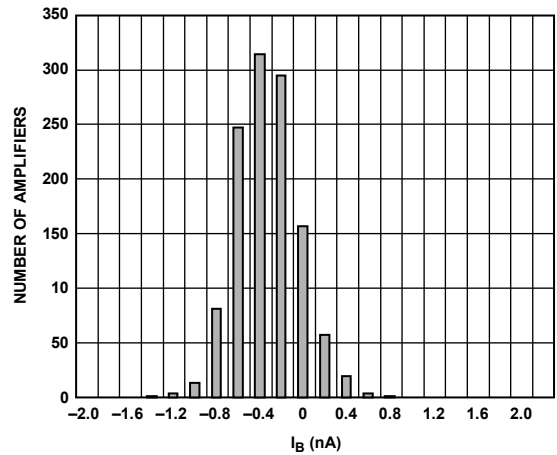


Figure 8. Input Bias Current, $V_{SY} = \pm 5\text{ V}$

06487-108

$\pm 15\text{ V}$ and $\pm 5\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

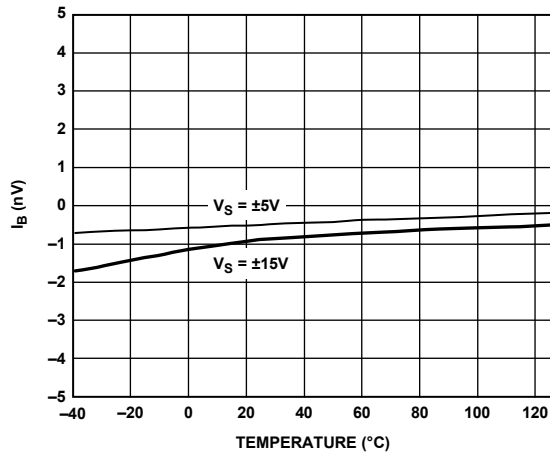


Figure 9. Input Bias Current vs. Temperature

06487-109

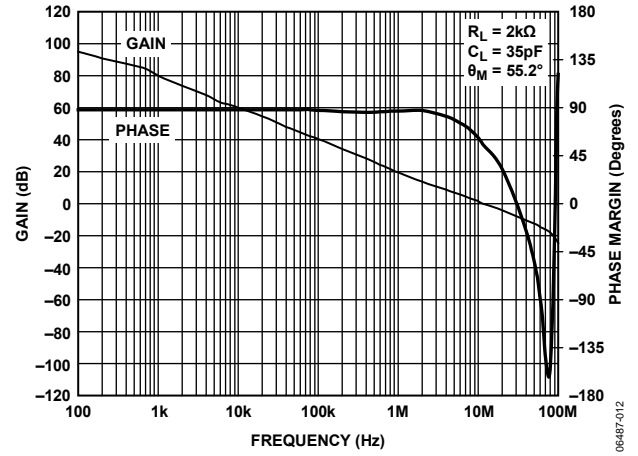


Figure 12. Gain and Phase vs. Frequency

06487-012

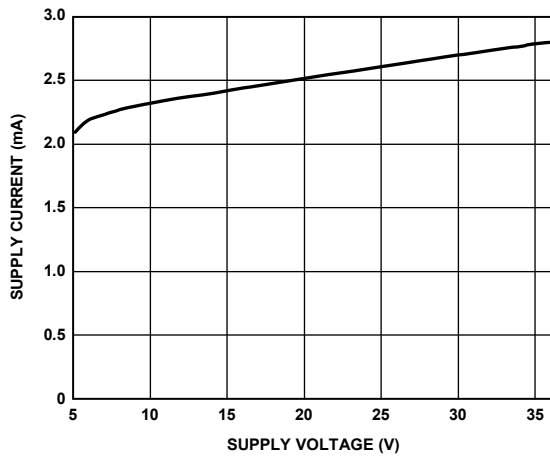


Figure 10. Supply Current vs. Total Supply Voltage

06487-110

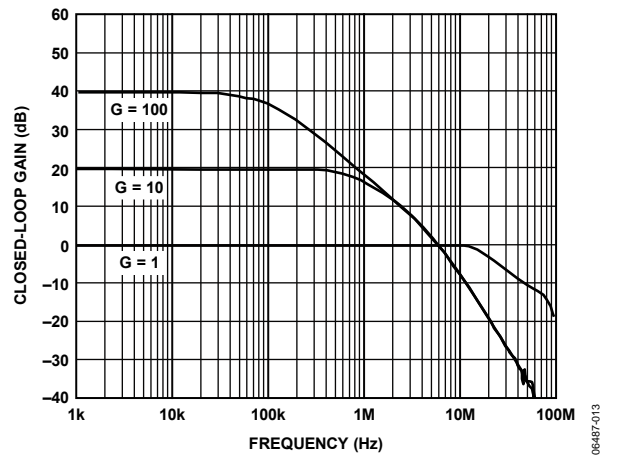


Figure 13. Closed-Loop Gain vs. Frequency

06487-013

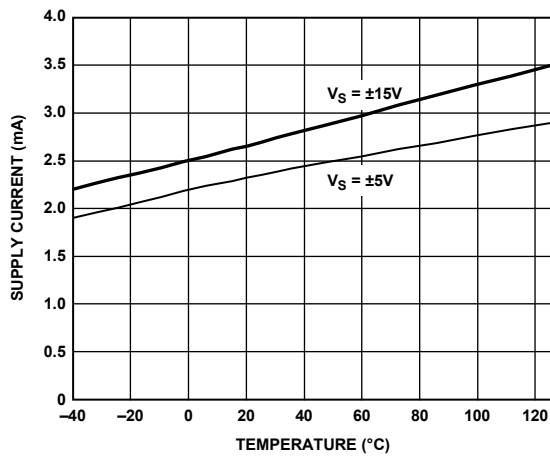


Figure 11. Supply Current vs. Temperature

06487-111

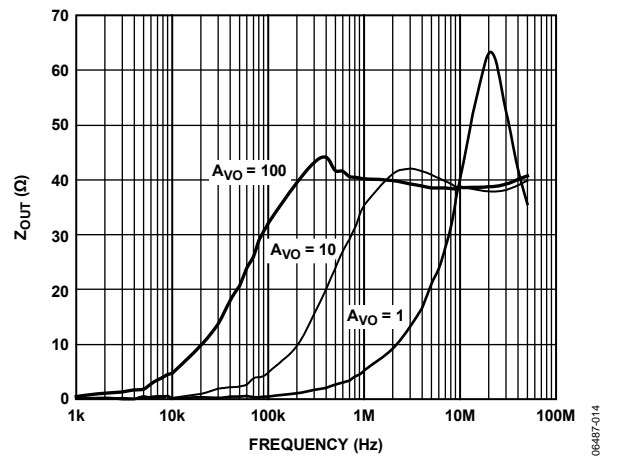


Figure 14. Z_{OUT} vs. Frequency

06487-014

$\pm 15\text{ V}$ and $\pm 5\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

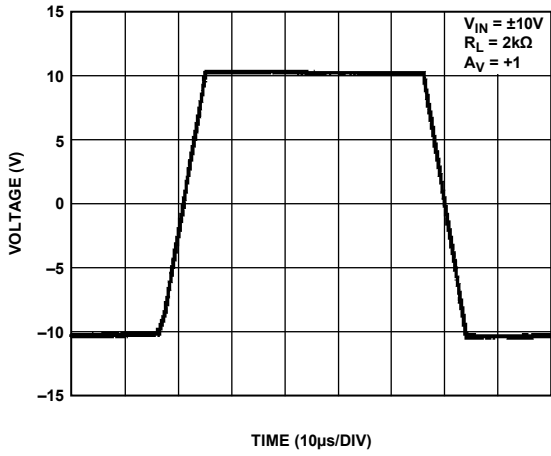


Figure 15. Large Signal Transient Response, $V_{SY} = \pm 15\text{ V}$

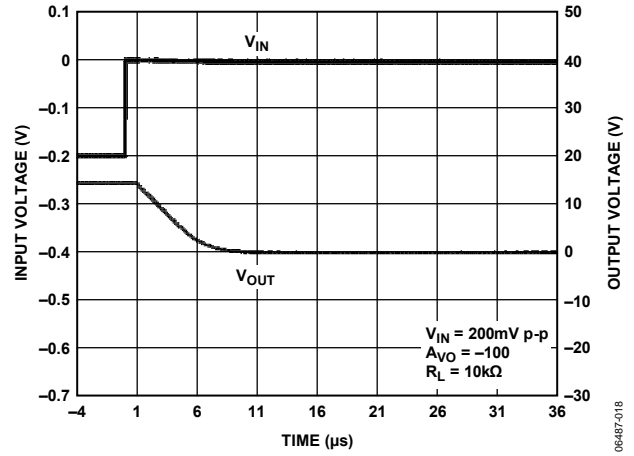


Figure 18. Positive Overvoltage Recovery

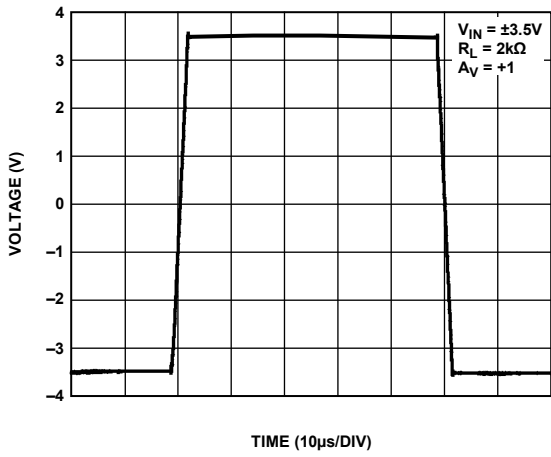


Figure 16. Large Signal Transient Response, $V_{SY} = \pm 5\text{ V}$

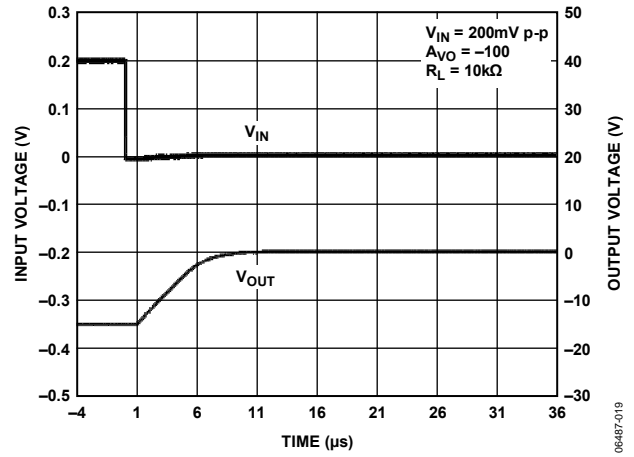


Figure 19. Negative Overvoltage Recovery

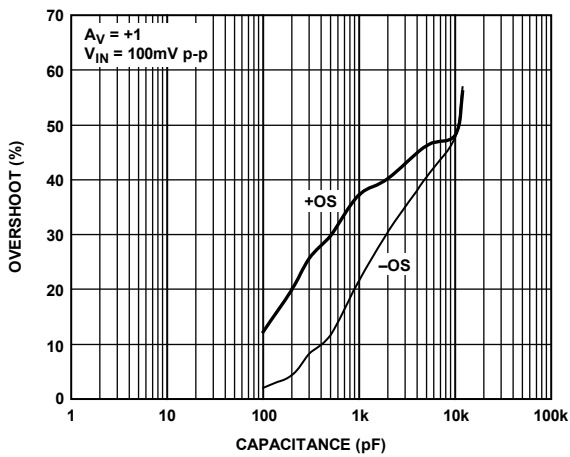


Figure 17. Small Signal Overshoot vs. Load Capacitance

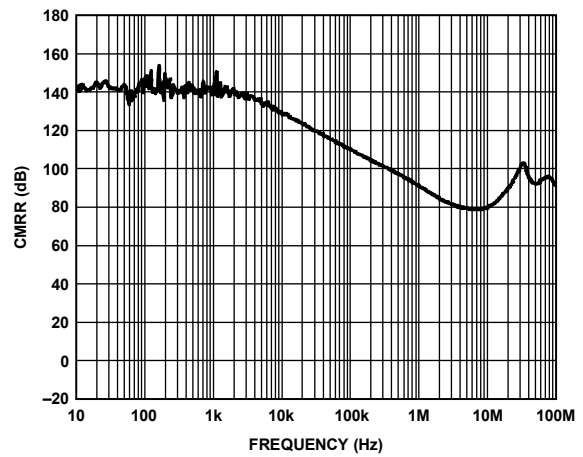


Figure 20. CMRR vs. Frequency

$\pm 15\text{ V}$ and $\pm 5\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

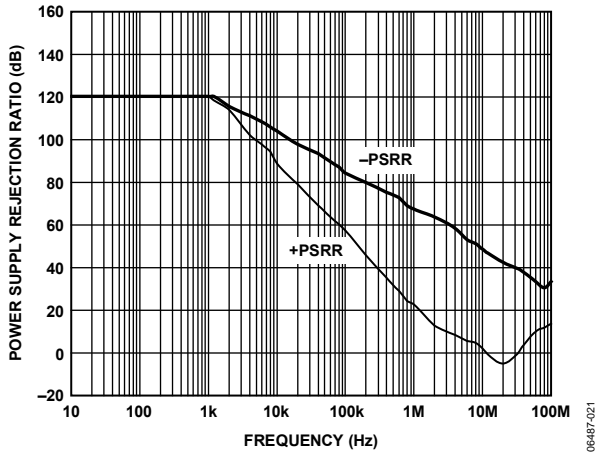


Figure 21. Power Supply Rejection Ratio vs. Frequency

06487-021

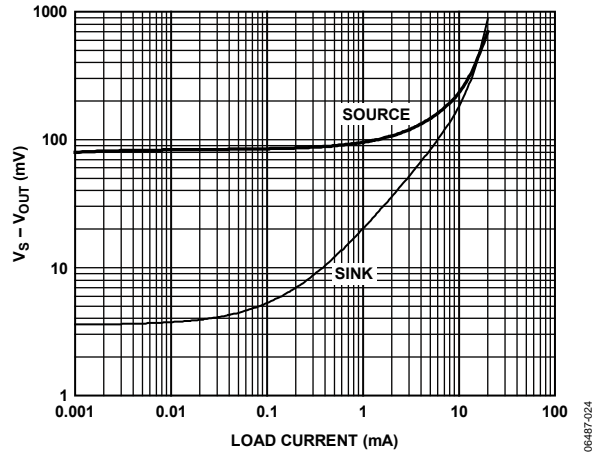


Figure 24. Output Saturation Voltage vs. Output Load Current

06487-024

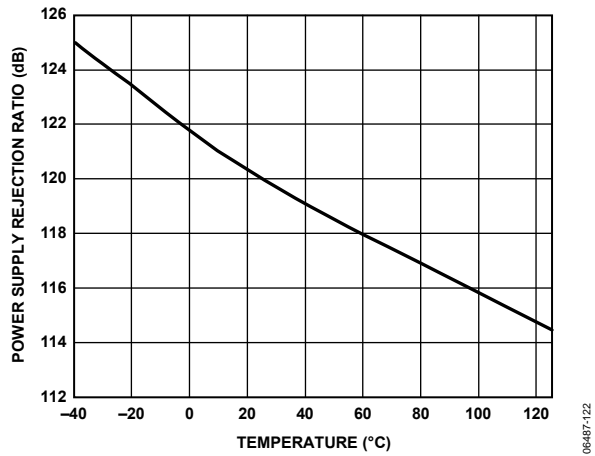


Figure 22. Power Supply Rejection Ratio vs. Temperature

06487-122

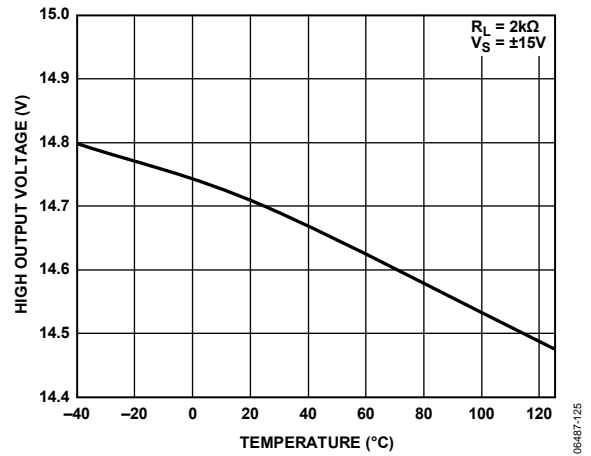


Figure 25. High Output Voltage, V_{OH} vs. Temperature, $V_S = \pm 15\text{ V}$

06487-125

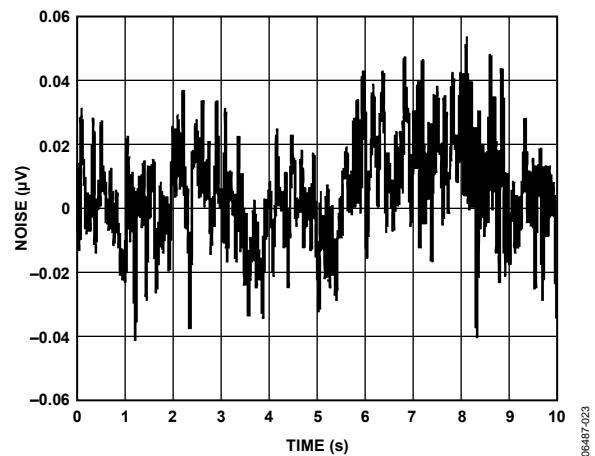


Figure 23. Voltage Noise (0.1 Hz to 10 Hz)

06487-023

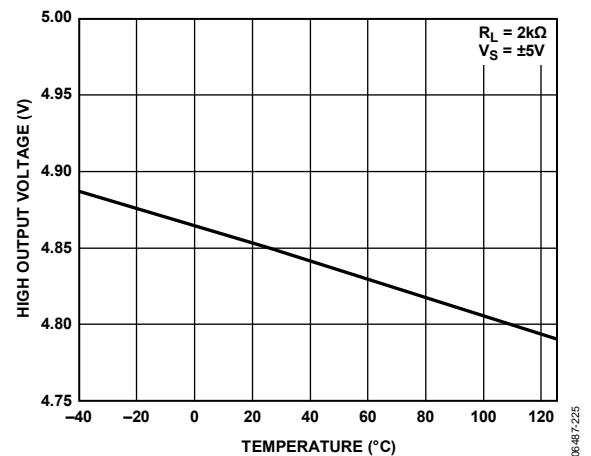


Figure 26. High Output Voltage, V_{OH} vs. Temperature, $V_S = \pm 5\text{ V}$

06-87-225

$\pm 15\text{ V}$ and $\pm 5\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

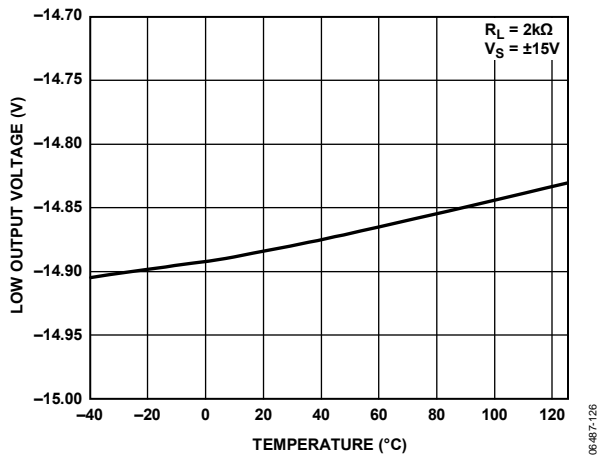


Figure 27. Low Output Voltage, V_{OL} vs. Temperature, $V_S = \pm 15\text{ V}$

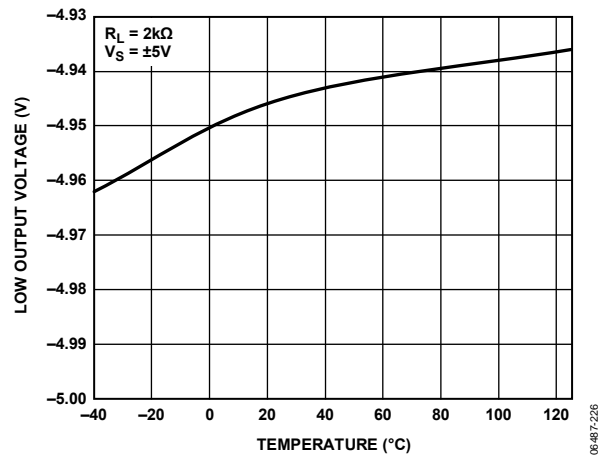


Figure 28. Low Output Voltage, V_{OL} vs. Temperature, $V_S = \pm 5\text{ V}$

OUTLINE DIMENSIONS

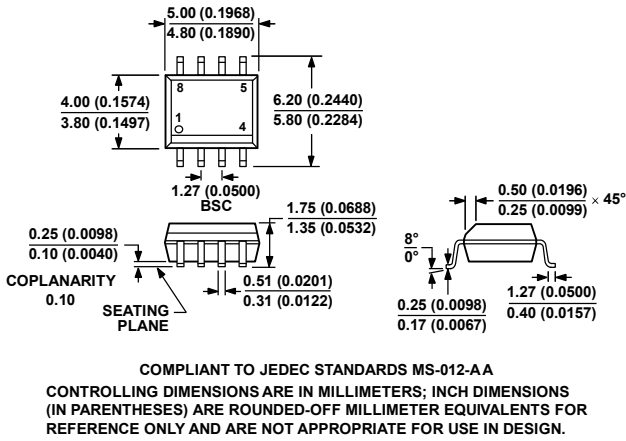


Figure 29. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body (R-8)
Dimensions shown in millimeters and (inches)

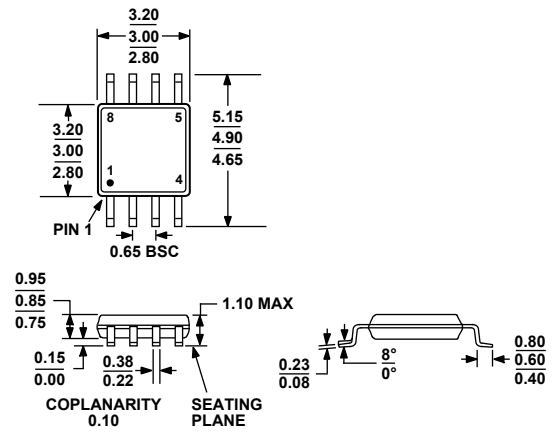


Figure 30. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)
Dimensions shown in millimeters

ORDERING GUIDE

| Model | Temperature Range | Package Description | Package Option | Branding |
|------------------------------|-------------------|--|----------------|----------|
| AD8676ARMZ-R2 ¹ | -40°C to +125°C | 8-Lead Mini Small Outline Package [MSOP] | RM-8 | A13 |
| AD8676ARMZ-REEL ¹ | -40°C to +125°C | 8-Lead Mini Small Outline Package [MSOP] | RM-8 | A13 |
| AD8676ARZ ¹ | -40°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 | |
| AD8676ARZ-REEL ¹ | -40°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 | |
| AD8676ARZ-REEL7 ¹ | -40°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 | |
| AD8676BRMZ-R2 ¹ | -40°C to +125°C | 8-Lead Mini Small Outline Package [MSOP] | RM-8 | A1L |
| AD8676BRMZ-REEL ¹ | -40°C to +125°C | 8-Lead Mini Small Outline Package [MSOP] | RM-8 | A1L |
| AD8676BRZ ¹ | -40°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 | |
| AD8676BRZ-REEL ¹ | -40°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 | |
| AD8676BRZ-REEL7 ¹ | -40°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 | |

¹ Z = RoHs Compliant Part.

AD8676

NOTES